



# 2SK4088LS

## N-Channel Power MOSFET 650V, 11A, 0.85Ω, TO-220F-3FS

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<http://onsemi.com>

### Features

- ON-resistance  $R_{DS(on)}=0.65\Omega$  (typ.)
- 10V drive
- Input capacitance  $C_{iss}=1000\text{pF}$  (typ.)

### Specifications

**Absolute Maximum Ratings at  $T_a=25^\circ\text{C}$** 

Parameter	Symbol	Conditions	Ratings	Unit
Drain to Source Voltage	$V_{DSS}$		650	V
Gate to Source Voltage	$V_{GSS}$		$\pm 30$	V
Drain Current (DC)	$I_{DC}^*1$	Limited only by maximum temperature $T_{ch}=150^\circ\text{C}$	11	A
	$I_{Dpack}^*2$	$T_c=25^\circ\text{C}$ (Our ideal heat dissipation condition)*3	7.5	A
Drain Current (Pulse)	$I_{DP}$	$PW \leq 10\mu\text{s}$ , duty cycle $\leq 1\%$	40	A
Allowable Power Dissipation	PD		2.0	W
		$T_c=25^\circ\text{C}$ (Our ideal heat dissipation condition)*3	37	W
Channel Temperature	$T_{ch}$		150	$^\circ\text{C}$
Storage Temperature	$T_{stg}$		-55 to +150	$^\circ\text{C}$
Avalanche Energy (Single Pulse) *4	EAS		65	mJ
Avalanche Current *5	$I_{AV}$		11	A

Note : \*1 Shows chip capability

\*2 Package limited

\*3 Our condition is radiation from backside.

The method is applying silicone grease to the backside of the device and attaching the device to water-cooled radiator made of aluminium.

 \*4  $V_{DD}=50\text{V}$ ,  $L=1\text{mH}$ ,  $I_{AV}=11\text{A}$  (Fig.1)

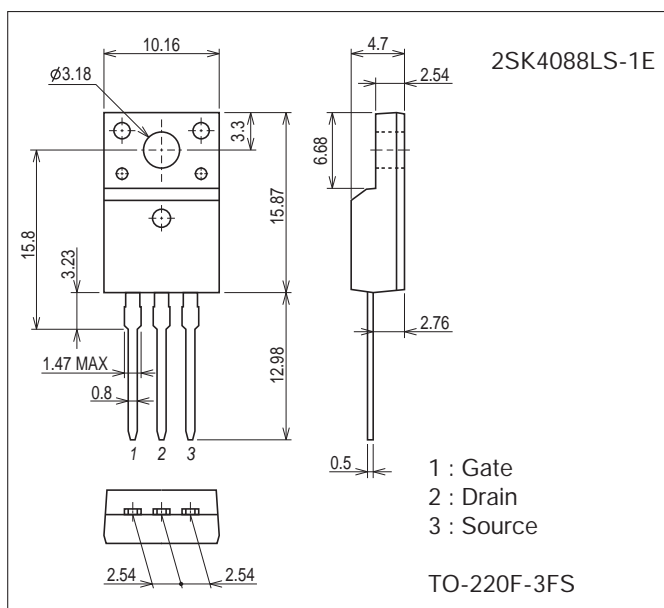
 \*5  $L \leq 1\text{mH}$ , single pulse

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

### Package Dimensions

unit : mm (typ)

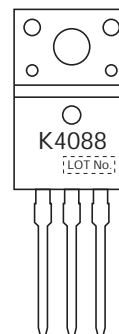
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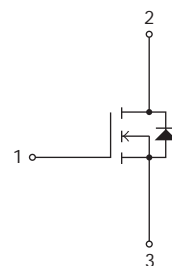
### Ordering & Package Information

Device	Package	Shipping	memo
2SK4088LS-1E	TO-220F-3FS, SC-67	50pcs./tube	Pb-Free

### Marking



### Electrical Connection



# 2SK4088LS

## Electrical Characteristics at Ta=25°C

Parameter	Symbol	Conditions	Ratings			Unit	
			min	typ	max		
Drain to Source Breakdown Voltage	$V_{(BR)DSS}$	$I_D=10mA, V_{GS}=0V$	650			V	
Zero-Gate Voltage Drain Current	$I_{DSS}$	$V_{DS}=520V, V_{GS}=0V$			100	$\mu A$	
Gate to Source Leakage Current	$I_{GSS}$	$V_{GS}=\pm 30V, V_{DS}=0V$			$\pm 100$	nA	
Cutoff Voltage	$V_{GS(off)}$	$V_{DS}=10V, I_D=1mA$	3		5	V	
Forward Transfer Admittance	$ y_{fs} $	$V_{DS}=10V, I_D=5.5A$	3.3	6.5		S	
Static Drain to Source On-State Resistance	$R_{DS(on)}$	$I_D=5.5A, V_{GS}=10V$		0.65	0.85	$\Omega$	
Input Capacitance	$C_{iss}$	$V_{DS}=30V, f=1MHz$		1000		pF	
Output Capacitance	$C_{oss}$				172		pF
Reverse Transfer Capacitance	$C_{rss}$				36		pF
Turn-ON Delay Time	$t_{d(on)}$	See specified Test Circuit.		24		ns	
Rise Time	$t_r$				58		ns
Turn-OFF Delay Time	$t_{d(off)}$				117		ns
Fall Time	$t_f$				40		ns
Total Gate Charge	$Q_g$	$V_{DS}=200V, V_{GS}=10V, I_D=11A$		37.6		nC	
Gate to Source Charge	$Q_{gs}$				6.8		nC
Gate to Drain "Miller" Charge	$Q_{gd}$				17.6		nC
Diode Forward Voltage	$V_{SD}$	$I_S=11A, V_{GS}=0V$		0.9	1.2	V	

Fig.1 Unclamped Inductive Switching Test Circuit

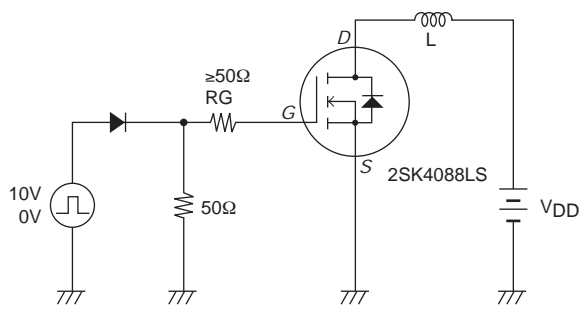
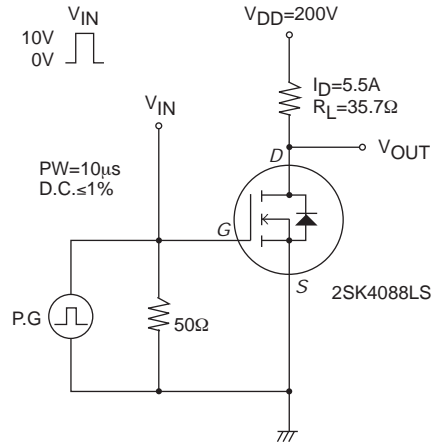
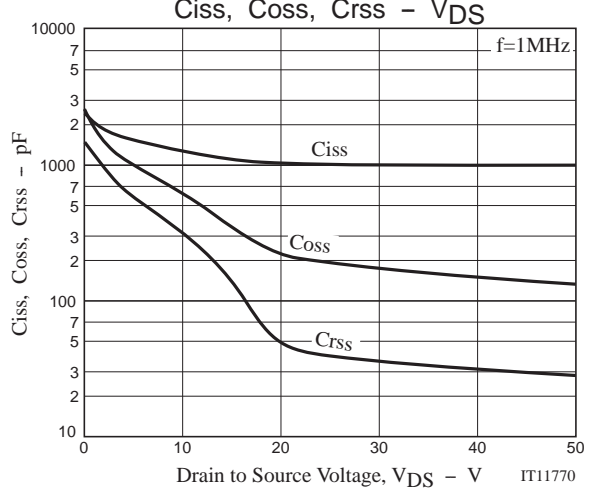
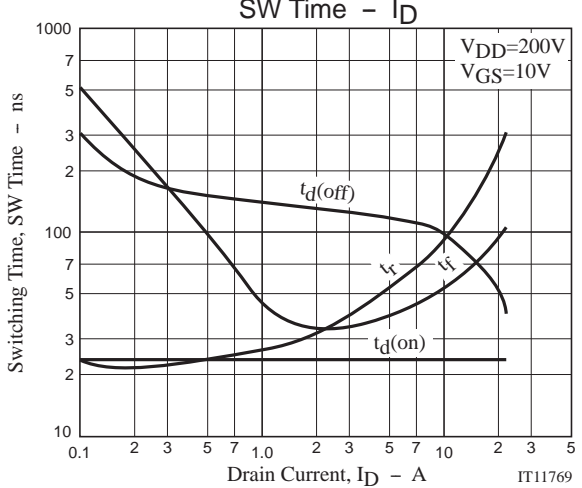
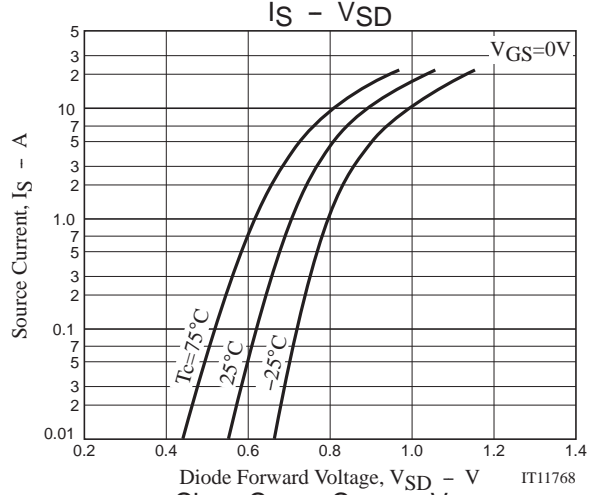
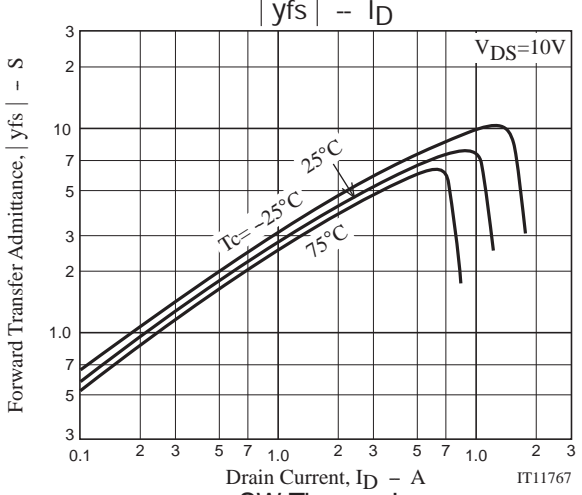
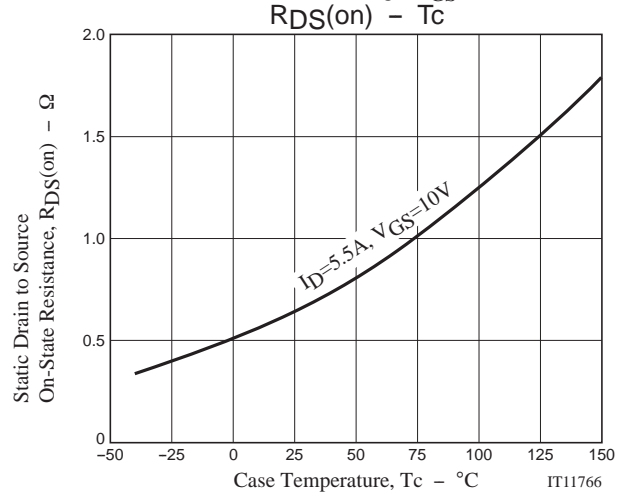
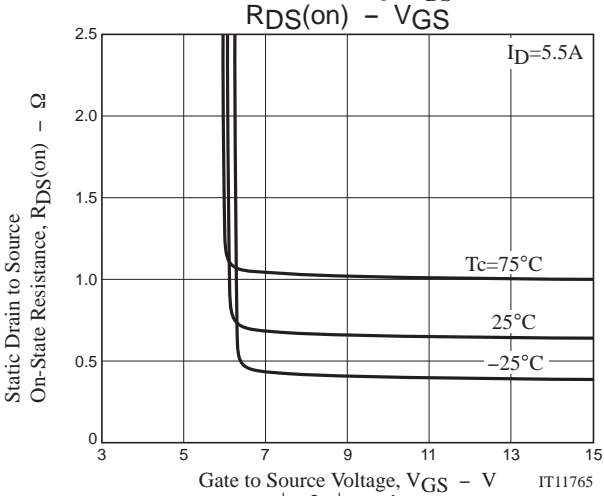
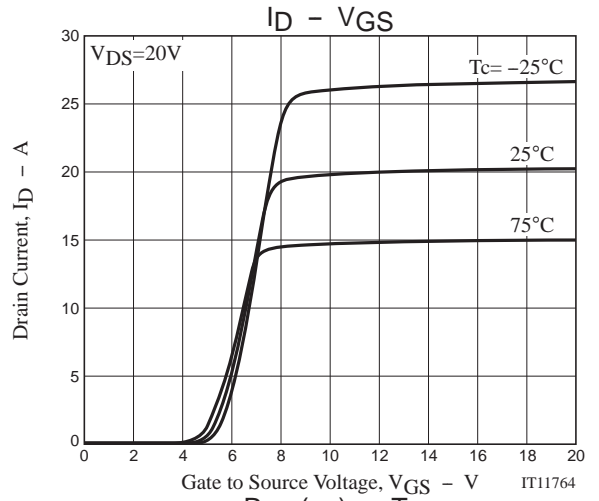
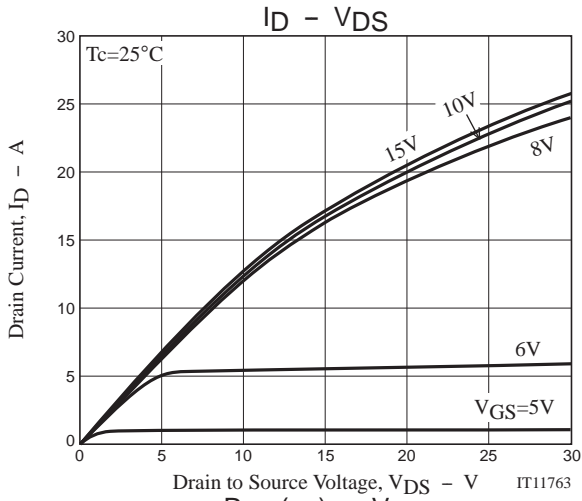
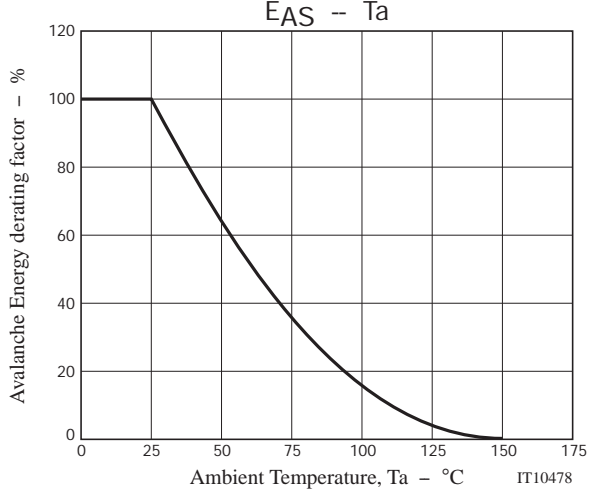
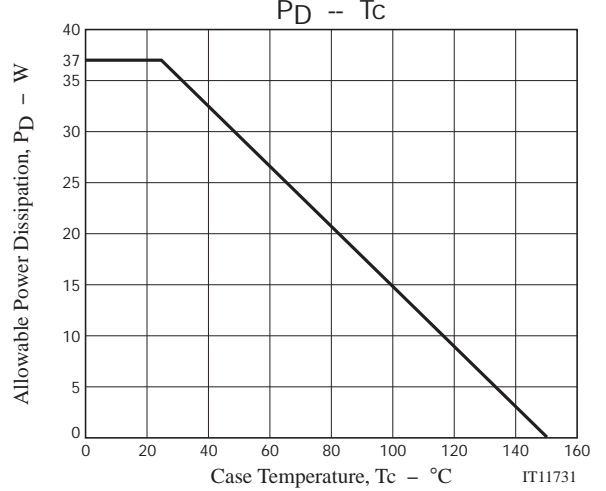
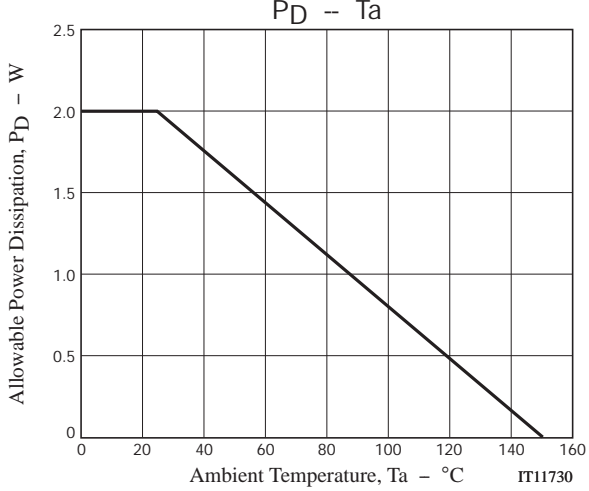
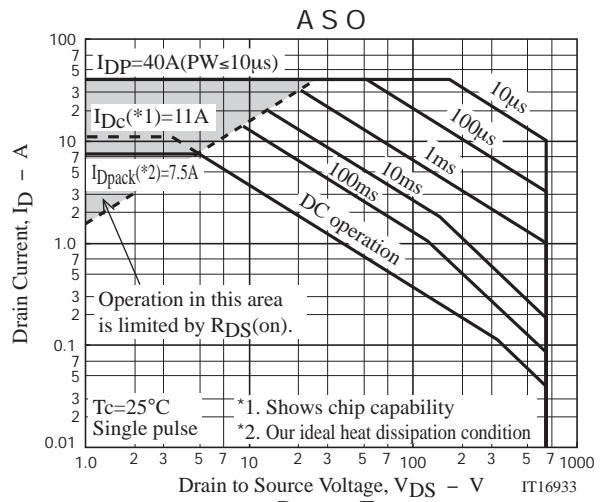
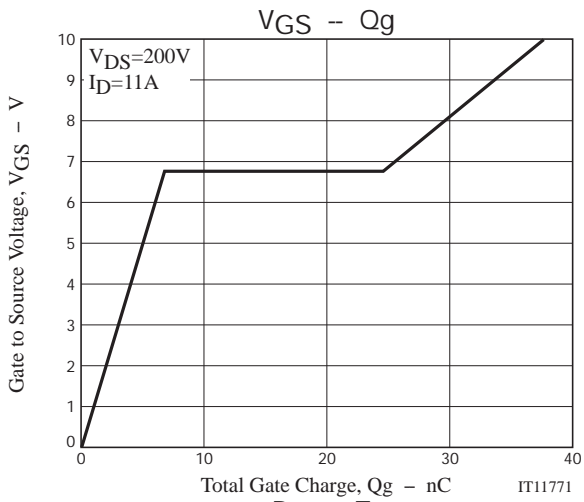


Fig.2 Switching Time Test Circuit



2SK4088LS





# 2SK4088LS

## Magazine Specification

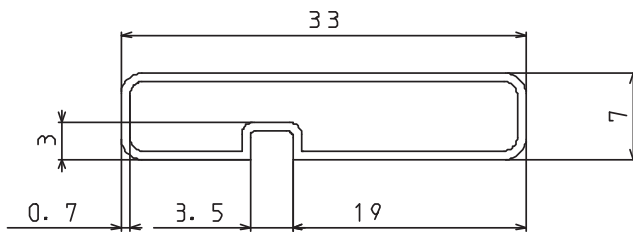
2SK4088LS-1E

### 1. Packing Format

Package Name	Magazine Name	Maximum Number of devices contained (pcs)			Packing format	
		Magazine	Inner box	Outer box	Inner BOX	Outer BOX
TO-220F-3FS	TO-220F	50	1,000	4,000	SPD-0V0001 20 magazines contained Dimensions:mm (external) 568×150×55	SPT-081029 4 inner boxes contained Dimensions:mm (external) 590×225×178

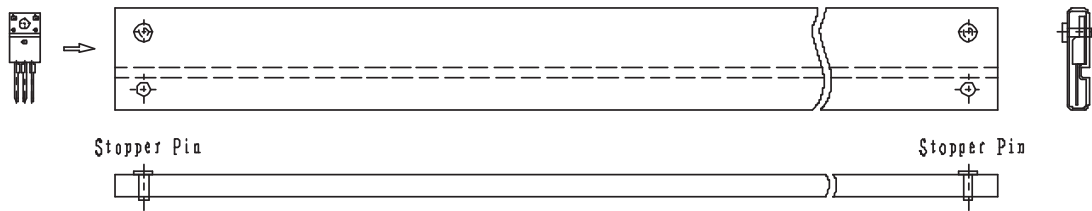
### 2. Magazine dimensions

(unit:mm)

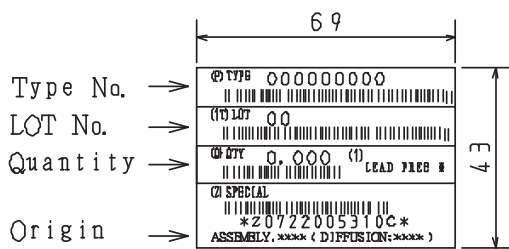


Tolerance=±0.3mm  
 Thickness=0.7±0.2mm  
 Length =532.5±2mm  
 Material =PVC (Antistatic treatment)

### 3. Storage method to magazine

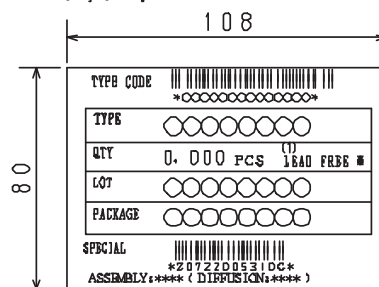


### 4. Inner box label (unit:mm)



### 5. Outer box label (unit:mm)

It is a label at the time of factory shipments.  
 The form of a label may change in physical  
 distribution process.



**NOTE (1)**

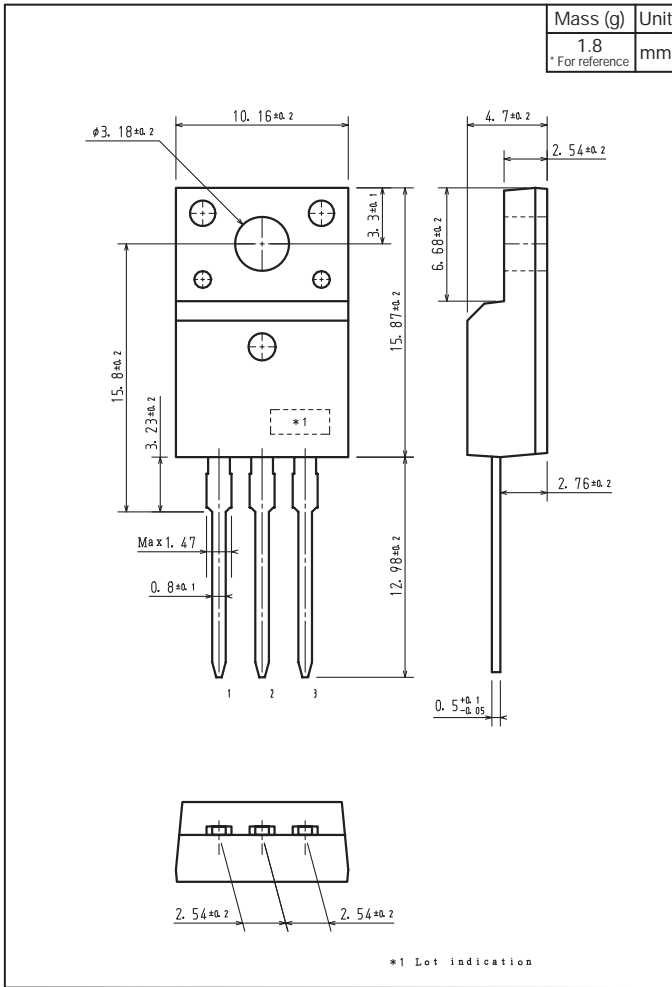
The LEAD FREE # description shows that the surface treatment of the terminal is lead free.

Label	JEITA Phase
LEAD FREE 3	JEITA Phase 3A

# 2SK4088LS

## Outline Drawing

2SK4088LS-1E



Note on usage : Since the 2SK4088LS is a MOSFET product, please avoid using this device in the vicinity of highly charged objects.

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